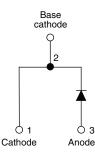
VS-HFA08PB60-N3

Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 8 A



www.vishay.com



PRIMARY CHARACTERISTICS					
I _{F(AV)}	8 A				
V _R	600 V				
V _F at I _F	1.4 V				
t _{rr} typ.	18 ns				
T _J max.	150 °C				
Package	TO-247AC 2L				
Circuit configuration	Single				

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

VS-HFA08PB60... is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 8 A continuous current, the VS-HFA08PB60... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA08PB60... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Cathode to anode voltage	V _R		600	V		
Maximum continuous forward current	١ _F	T _C = 100 °C	8			
Single pulse forward current	I _{FSM}	t _p = 10 ms	60	А		
Maximum repetitive forward current	I _{FRM}		24			
Maximum nawar discipation	P _D	T _C = 25 °C	36	14/		
Maximum power dissipation		T _C = 100 °C	14	W		
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C		

RoHS COMPLIANT HALOGEN FREE

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ELECTRICAL SPECIFICATIONS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		600	-	-	
		I _F = 8.0 A		-	1.4	1.7	v
Maximum forward voltage	oltage V _{FM}	I _F = 16 A	See fig. 1	-	1.7	2.1	
		$I_F = 8.0 \text{ A}, T_J = 125 \text{ °C}$		-	1.4	1.7	
Maximum reverse		$V_{R} = V_{R}$ rated	0	-	0.3	5.0	μA
leakage current	I _{RM}	T_J = 125 °C, V_R = 0.8 x V_R rated	See fig. 2	-	100	500	
Junction capacitance	CT	V _R = 200 V See fig. 3		-	10	25	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body - 8.0 - nH			nH		

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
	t _{rr}	I _F = 1.0 A, dI _F /dt = 200 A/μs, V _R = 30 V		-	18	-	
Reverse recovery time See fig. 5, 10	t _{rr1}	T _J = 25 °C		-	37	55	ns
000 lig. 0, 10	t _{rr2}	T _J = 125 °C		-	55	90	
Peak recovery current	I _{RRM1}	T _J = 25 °C	I _F = 8.0 A dI _F /dt = 200 A/µs V _R = 200 V	-	3.5	5.0	А
See fig. 6	I _{RRM2}	T _J = 125 °C		-	4.5	8.0	A
Reverse recovery charge	Q _{rr1}	T _J = 25 °C		-	65	138	nC
See fig. 7	Q _{rr2}	T _J = 125 °C		-	124	360	ne
Peak rate of fall of recovery	dl _{(rec)M} /dt1	T _J = 25 °C		-	240	-	A /uo
current during t _b See fig. 8	dl _{(rec)M} /dt2	T _J = 125 °C		-	210	-	A/µs

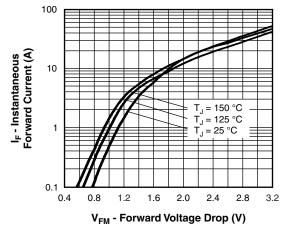
THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C	
Thermal resistance, junction to case	R _{θJC}		-	-	3.5		
Thermal resistance, junction to ambient	R _{θJA}	Typical socket mount	-	-	40	K/W	
Thermal resistance, case to heatsink	$R_{\theta CS}$	Mounting surface, flat, smooth, and greased	-	0.25	-		
Weight			-	6.0	-	g	
Weight			-	0.21	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-247AC 2L	HFA08PB60				

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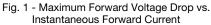
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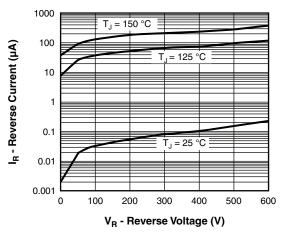


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

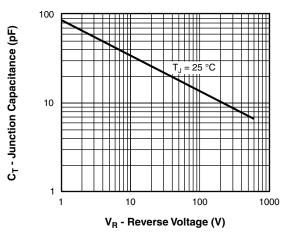


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

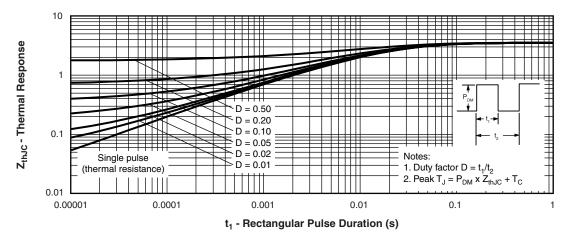


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



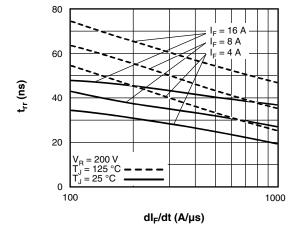


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt (Per Leg)

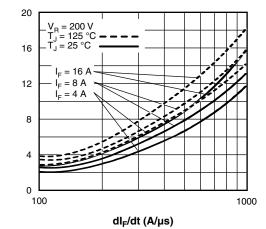


Fig. 6 - Typical Recovery Current vs. dl_F/dt (Per Leg)

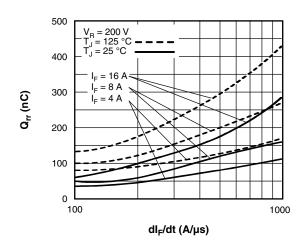


Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Leg)

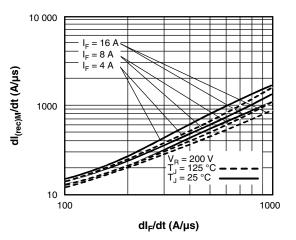


Fig. 8 - Typical dI_{(rec)M}/dt vs. dI_F/dt (Per Leg)

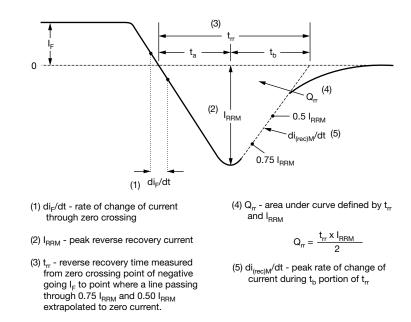


Fig. 9 - Reverse Recovery Waveform and Definitions

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VS-HFA08PB60-N3

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ORDERING INFORMATION TABLE

Device code	VS-	HF	Α	08	РВ	60	-N3
		2	3	4	5	6	7
	1 · 2 · 3 · 4 · 5 ·	· HE · Elec · Cur · PB	KFRED [®] ctron irra rent rati = TO-24		= 8A) pins		
	7 -	Env	ironmer	ntal digit en-free,	:		int, and

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-HFA08PB60-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96144					
Part marking information www.vishay.com/doc?95648					



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